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A 0D hybrid lead-free halide with near-unity photoluminescence quantum yield toward multifunctional optoelectronic applications†

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Zero-dimensional (0D) hybrid metal halides have emerged as highly efficient luminescent materials, but integrated multifunction in a structural platform remains a significant challenge. Herein, a new hybrid 0D indium halide of (Im-BDMPA)InCl₆·H₂O was designed as a highly efficient luminescent emitter and X-ray scintillator toward multiple optoelectronic applications. Specifically, it displays strong broadband yellow light emission with near-unity photoluminescence quantum yield (PLQY) through Sb³⁺ doping, acting as a down-conversion phosphor to fabricate high-performance white light emitting diodes (WLEDs). Benefiting from the high PLQY and negligible self-absorption characteristics, this halide exhibits extraordinary X-ray scintillation performance with a high light yield of 55 320 photons per MeV, which represents a new scintillator in 0D hybrid indium halides. Further combined merits of a low detection limit (0.0853 μGy_{air} s⁻¹), ultra-high spatial resolution of 17.25 lp per mm and negligible afterglow time (0.48 ms) demonstrate its excellent application prospects in X-ray imaging. In addition, this 0D halide also exhibits reversible luminescence off–on switching toward tribromomethane (TBM) but fails in any other organic solvents with an ultra-low detection limit of 0.1 ppm, acting as a perfect real-time fluorescent probe to detect TBM with ultrahigh sensitivity, selectivity and repeatability. Therefore, this work highlights the multiple optoelectronic applications of 0D hybrid lead-free halides in white LEDs, X-ray scintillation, fluorescence sensors, etc.

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Introduction

In the past several decades, halide perovskite nanocrystals (PNCs) of CsPbX₃ (X = Cl, Br, I) have emerged as new-generation optoelectronic functional materials due to excellent optical and electronic properties including direct bandgaps, high absorption coefficients, low defect densities, long carrier diffusion lengths, etc.^{1–4} PNCs display excellent photoluminescence (PL) performance with diversified advantages of an adjustable emission wavelength covering the whole visible spectrum, narrow bandwidth, high photoluminescence quantum yield (PLQY), etc.^{5–8} Therefore, three-dimensional (3D) PNCs have been explored as down-conversion phosphors to fabricate solid-

state LED and backlit liquid-crystal display (LCD) devices with high external quantum efficiency and a wide color gamut, respectively.^{9–11} Since 2018, 3D PNCs have been explored as new a kind of scintillator due to their strong X-ray absorption and conversion ability, which aroused new research interest to explore their application in radiation detection and X-ray imaging.^{12,13} In addition, the unique crystal structure and dynamic ionic bond nature also endow 3D PNCs with a PL switching phenomenon as fluorescence sensors toward external stimuli.^{14–16} As a consequence, 3D PNCs possess widely advanced application prospects in LEDs, photovoltaic cells, photodetectors, lasers, scintillators, fluorescent probes, etc.^{17–19} Despite multiple optoelectronic performances, some inescapable shortcomings (such as spectral instability, toxic Pb²⁺ ions, low scintillation light yield, irreversible PL switching, etc.) remain, seriously restricting the application prospects of 3D PNCs, which inspire further in-depth research to explore new environmentally friendly perovskite derivatives to overcome these drawbacks.

Recently, organic–inorganic hybrid zero-dimensional (0D) metal halide perovskites have attracted tremendous attention as some of the promising candidates of 3D PNCs with comparable optoelectronic properties and superior stabilities.^{20–23} Indeed, versatile organic species and substantial metal ions

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(Cu⁺, Mn²⁺, Zn²⁺, In³⁺, Sb³⁺, *etc.*) endow hybrid metal halides with diversified structural architectures and PL properties.^{24–27} Especially, the intrinsic strong quantum confinement and highly localized electrons result in large exciton bonding energy, giving rise to ultrahigh PLQY even up to near unity for 0D hybrid metal halides. The soft crystal lattice readily vibrates with photo-induced excitons as strong electron–phonon coupling, resulting in largely Stokes-shifted broadband light emission.^{28,29} As a consequence, these 0D hybrid metal halides can be utilized as down-conversion single-component white light phosphors to fabricate LEDs such as (HMTA)₄PbMn_{0.69}Sn_{0.31}Br₈, [Bmim]₂SbCl₅, *etc.*^{30,31} More significantly, some 0D hybrid metal halides have been further explored as X-ray scintillators with impressive light yield under X-ray excitation due to high PLQY and large Stokes shift.^{32,33} For instance, 0D Mn²⁺ and Cu⁺ based halides display extraordinary scintillation performance with light yield exceeding 80 000 photons per MeV, which is far superior to that of typical 3D CsPbX₃ PNCs (~21 000 photons per MeV) and commercial scintillators, such as CsI:Tl (54 000 photons per MeV), Gd₂O₂S:Tb (60 000 photons per MeV), *etc.*^{34–36} In addition, the softer crystal lattice endows 0D hybrid halides with more opportunities to accommodate or recognize small molecules accompanied by change of luminescence properties, acting as a special fluorescent probe with high selectivity and sensitivity.³⁷ Therefore, 0D hybrid metal halides provide an optimal structural platform to realize highly desirable luminescence performance with multiple state-of-the-art optoelectronic applications.^{38,39} Undoubtedly, ultra-high PLQY and large Stokes shift are crucial for 0D hybrid halides as either down-conversion phosphors or X-ray scintillators to achieve high luminous efficacy and light yield.

Among these 0D hybrid metal halides, indium based halides are deemed to be some of the most promising light emitters with multiple superiorities including diversified coordination configurations of [InX₄][–], [InX₅]^{2–} and [InX₆]^{3–}, non-toxicity, oxidation resistance ability, *etc.*^{40,41} Compared with the instabilities of Sn²⁺ and Ge²⁺ halides, low efficiencies of Bi³⁺ phases, nearly fixed green or red spectral emission of Mn²⁺ based halides, yellow to orange color of Sb³⁺ halides and blue emission of Zn²⁺ halides, 0D In³⁺-based halides represent some of the most desirable light emitters with multiple advantages including tunable light emissions in the whole visible spectral range, nontoxicity, high emission efficiency, strong oxidation resistance ability, *etc.*^{42,43} In addition, some 0D hybrid indium halides have been confirmed to display reversible PL switching toward external chemical stimuli as a fluorescent probe to detect small molecules, such as H₂O, methanol, *etc.*^{44,45} However, the highest PLQY (<60%) of 0D hybrid indium halides lags far behind those of Mn²⁺ and Cu⁺ based halides. More miserably, no 0D hybrid indium halide has been able to act as an X-ray scintillator due to low PLQY up to now. These insufficiencies attract new research attention towards designing a new kind of 0D hybrid indium halide to realize highly efficient photoluminescence and radioluminescence through crystal engineering at the molecular level.

In view of these shortcomings, we focus on this domain to explore highly efficient emissive 0D hybrid indium halides

aiming to realize multiple advanced optoelectronic applications, especially for solid-state white LEDs and X-ray scintillation. In this work, we prepared a new 0D hybrid indium halide (Im-BDMPA)InCl₆·H₂O (Im-BDMPA = 3,3'-iminobis(*N,N*-dimethylpropylamine)) based on discrete [InCl₆]^{3–} octahedra *via* a facile wet-chemistry or mechanical grinding solid-phase reaction method. Through rational Sb³⁺ doping, highly efficient broadband yellow PL emission with near-unity PLQY and a large Stokes shift of 1.28 eV is achieved for all states in single-crystal, microparticle and flexible composite films. Unexpectedly, the Sb³⁺ doped (Im-BDMPA)InCl₆·H₂O displays extraordinary X-ray scintillation performance with a high light yield of 55 320 photons per MeV. Although numerous manganese or cuprous halides have been characterized as scintillators, an indium halide based X-ray scintillator has rarely been reported and Sb³⁺ doped (Im-BDMPA)InCl₆·H₂O represents a new example of indium halides. Simultaneously, this 0D hybrid indium halide also represents the first luminescent material acting as a unique fluorescent probe toward TBM with ultrahigh sensitivity, selectivity and repeatability. Overall, this 0D halide showcases multiple optoelectronic applications in white LEDs, X-ray scintillation and fluorescence sensors, which opens a broad application window for 0D hybrid halides as promising luminescent materials.

Results and discussion

Bulk single crystals of (Im-BDMPA)InCl₆·H₂O were prepared *via* a typical low-temperature solvothermal reaction method. Based on single crystal X-ray diffraction, the structure of (Im-BDMPA)InCl₆·H₂O crystallizes in the orthorhombic space group *P*2₁2₁2₁ and composed of discrete [InCl₆]^{3–} octahedra surrounded by bulk (Im-BDMPA)³⁺ cations. All the In³⁺ ions are surrounded by six Cl[–] ions in [InCl₆]^{3–} octahedra with In–Cl bond distances in the normal range of 2.5009(6)–2.5452(6) Å (Fig. 1a). All the neighboring [InCl₆]^{3–} octahedrons are separated by long (Im-BDMPA)³⁺ cations to form a 0D hydrogen bonding structure at the molecular level (Fig. 1b). The sample purity and high crystalline degree of (Im-BDMPA)InCl₆·H₂O are revealed by matched experimental and simulated powder X-ray diffraction (PXRD) patterns (Fig. 1c). The distributions of the respective chemical compositions have been checked using energy dispersive X-ray spectroscopy (EDS), elemental mapping images, *etc.* (Fig. S1† and 1d). Sb³⁺-doped (Im-BDMPA)InCl₆·H₂O was synthesized by adding the desired amount of SbCl₃ into the original synthesis process of the single indium phase, and the coincident PXRD pattern indicates the same crystal structure (Fig. 1c). The chemical composition and successful Sb doping were further confirmed by EDS and elemental mapping, and the optimized doping concentration of Sb element was determined to be 22% by inductively coupled plasma optical emission spectroscopy (ICP-OES) (Fig. S2† and 1d). Subsequently, high-quality (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O microcrystals were synthesized as an example through a microwave irradiation assisted mechanical stripping method and finally shows a nearly cubic shape with a particle size less than <5 μm (Fig. 1e). The identical diffraction peaks in the PXRD pattern



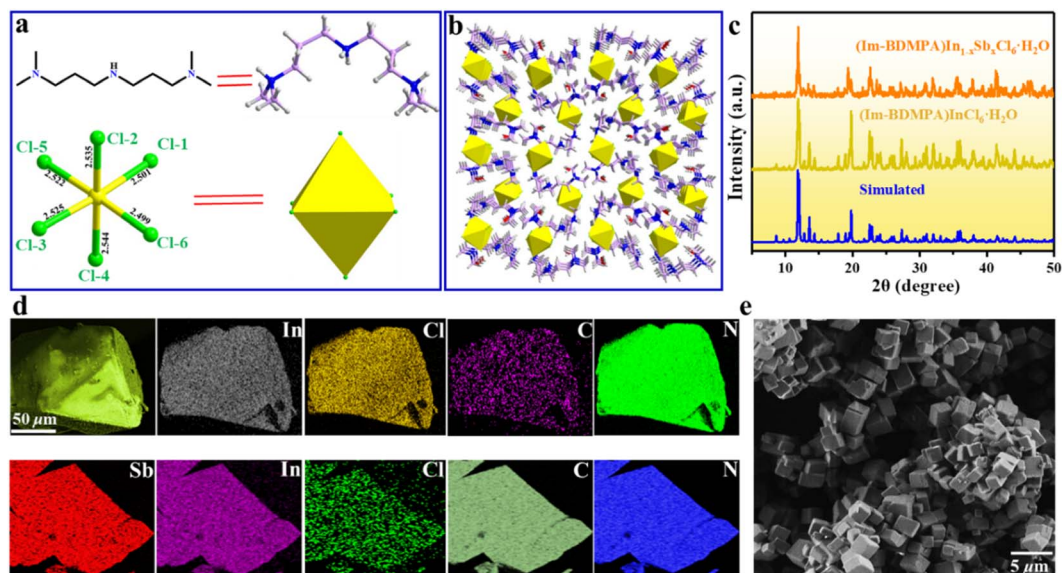


Fig. 1 Structural characterization of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$: (a) $(\text{Im-BDMPA})^{3+}$ cation and $[\text{In/SbCl}_6]^{3-}$ octahedron; (b) packing structure of the OD structure viewed along the a -axis; (c) simulated and experimental PXRD patterns; (d) elemental mapping of SEM images; (e) SEM image of a microparticle.

indicate the high crystalline degree of microcrystals (Fig. S3†). $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ microcrystals can also be prepared by a solid-phase mechanochemical grinding method from precursor materials within a fast time of 30 s and with 100% yield verified by the same PXRD pattern, providing a facile

preparation method for various optoelectronic device engineering (Fig. S4 and S5†).

As shown in Fig. 2a and S6,† bulk single crystals of pristine and doped $(\text{Im-BDMPA})\text{InCl}_6 \cdot \text{H}_2\text{O}$ display the same bright yellow light emission under UV light radiation. The PL properties of $(\text{Im-BDMPA})\text{InCl}_6 \cdot \text{H}_2\text{O}$ are summarized in Fig. S6,† and

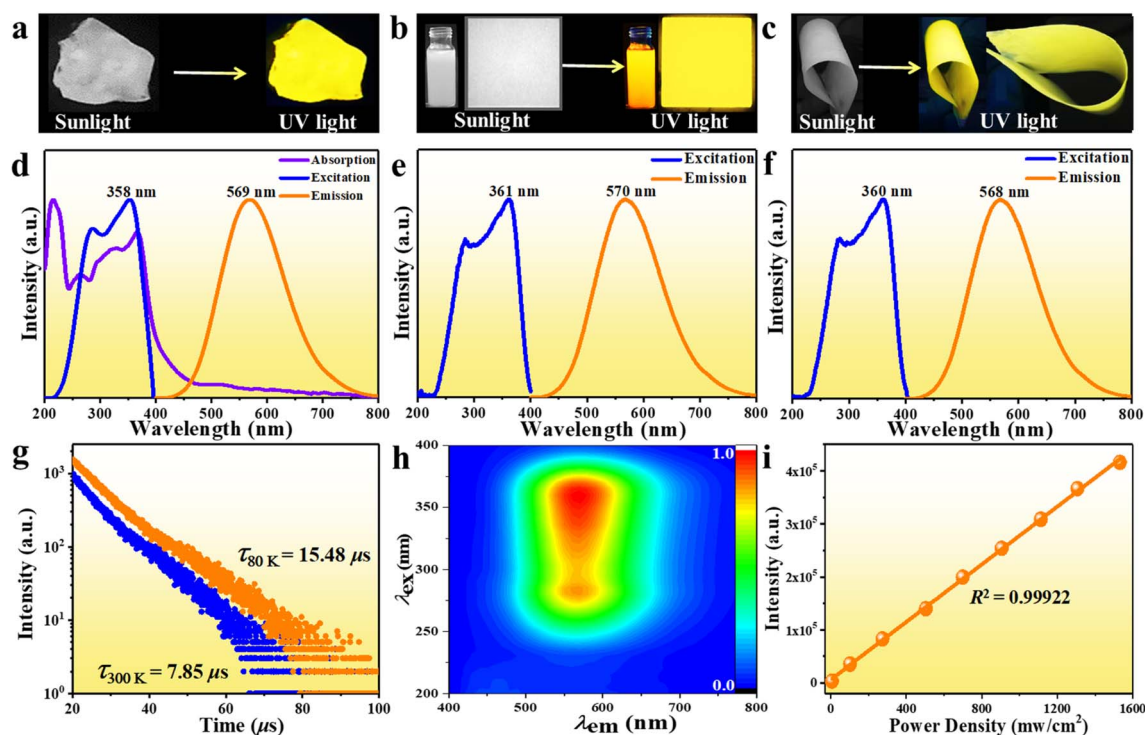


Fig. 2 PL characterization of $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$: (a–c) photo images of bulk crystals, microparticles, the deposited thin film and the flexible composite film under sunlight and 365 nm UV light; (d–f) absorption, excitation and emission spectra of bulk crystals, microparticles and flexible composite; (g) PL decay curves at 300 K and 80 K; (h) 3D consecutive PL map; (i) power density dependent PL emission intensity.



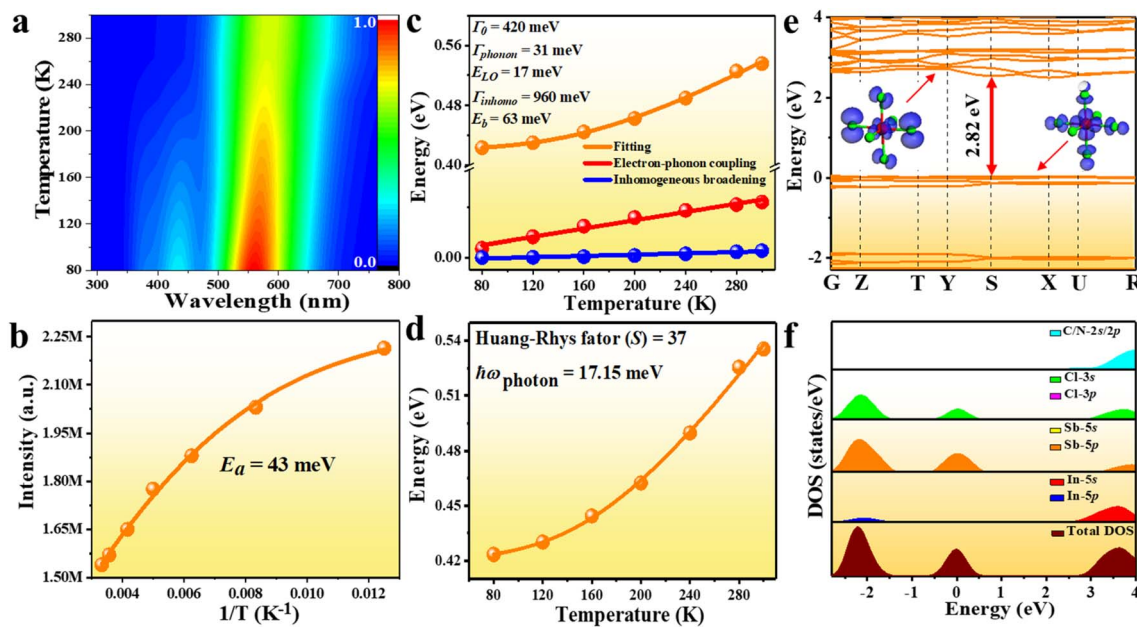


Fig. 3 PL mechanism study of $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$: (a) 3D color mapping of PL emission at varied temperature; (b) experimental and fitted emission intensity vs. reciprocal temperature; (c) temperature-dependent FWHM with the contribution of electron-phonon coupling and inhomogeneous broadening; (d) fitted FWHM according to eqn (2); (e) electronic band structure (inset: electron density maps of the HOMO and LUMO); (f) total and partial densities of states.

recombination of STE due to EP coupling in the soft crystal lattice. The detailed PL mechanism was further unveiled by using density functional theory (DFT) calculations. As shown in Fig. S16[†] and 3e, the incorporation of Sb^{3+} into pure 0D indium perovskite induces an isolated and extremely narrow impurity band in valence bands, which reduces the band gap from 4.2 eV to 2.82 eV. Owing to the absence of electronic interactions between adjacent anionic octahedra, both the conduction and valence bands are fairly flat illustrating highly localized electron states with large effective mass, promoting the formation of electron and hole polarons.⁵⁰ However, the conduction bands remain unchanged meaning that the incorporation of Sb^{3+} mainly leads to up-shift of the VBM. Detailed density of states and electron maps show that both the CBM and VBM are contributed by anionic species without direct contribution from the organic component (Fig. 3e and f). Therefore, the corporation of Sb^{3+} does not influence the radiative recombination process but introduces new impurity bands, increases the electron state density of VBM, facilitates more carriers into the conduction band, and finally improves the emission efficiency.⁵¹

Apart from the highly efficient broadband light emission, $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ also exhibits sufficient structural and spectral stability. Based on thermogravimetric analysis, the bulk crystals of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ can be stable up to about 280 °C (Fig. S17[†]). Under continuous heating at different temperatures from 80 °C to 280 °C, the PL emission spectral profiles remain unchanged with slightly decreased intensities and PXRD patterns are also fixed indicating sufficient thermal stability (Fig. S18[†]). After long-term exposure to humid air for one month or strong UV light for 48 h, $(\text{Im-}$

$\text{BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ retains the high crystalline degree and nearly identical emission intensity (Fig. S19[†]). Highly efficient and stable broadband (FWHM = 135 nm) yellow light emission motivates us to fabricate a white LED by using $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ as a down-conversion phosphor. To validate this application, we firstly blend $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ as a yellow phosphor and commercial $\text{BaMgAl}_{10}\text{O}_{17}:\text{Eu}^{2+}$ as a blue phosphor with varied ratios. As shown in Fig. 4a and b, the mechanically mixed phosphors display white light emission under irradiation of 365 nm UV light and broadband PL spectra are composed of dual blue-yellow emitting peaks. By finely controlling the blending ratio of the two phosphors, a range of “cold” to “warm” white light can be obtained with tunable correlated color temperature (CCT) from 9520 K to 3320 K (Fig. 4c and Table S2[†]). Subsequently, a white LED was fabricated as an example by coating the mixed phosphor on an UV chip. Under the drive of 20 mA current, the LED gives bright white light with a CCT of 4590 K and CIE chromaticity coordinates of (0.35, 0.33) (Fig. 4d and e). The obtained color rendering (CRI) index of 95.4 is far higher than that of commercially available white LEDs based on $\text{YAG}:\text{Ce}^{3+}$ (CRI < 80).³¹ To test the reabsorption effect between the two phosphor counterparts, varied electroluminescence (EL) spectra under different operating currents were recorded (Fig. 4f). With the current increasing from 20 mA to 120 mA, both the EL emission intensities of dual emission peaks increase linearly with enhanced drive current without energy transfer between the two phosphors, showcasing potential application in high-power white LEDs. The CIE coordinates, CCT and CRI also keep almost unchanged indicating the negligible self-absorption and efficiency loss of the fabricated



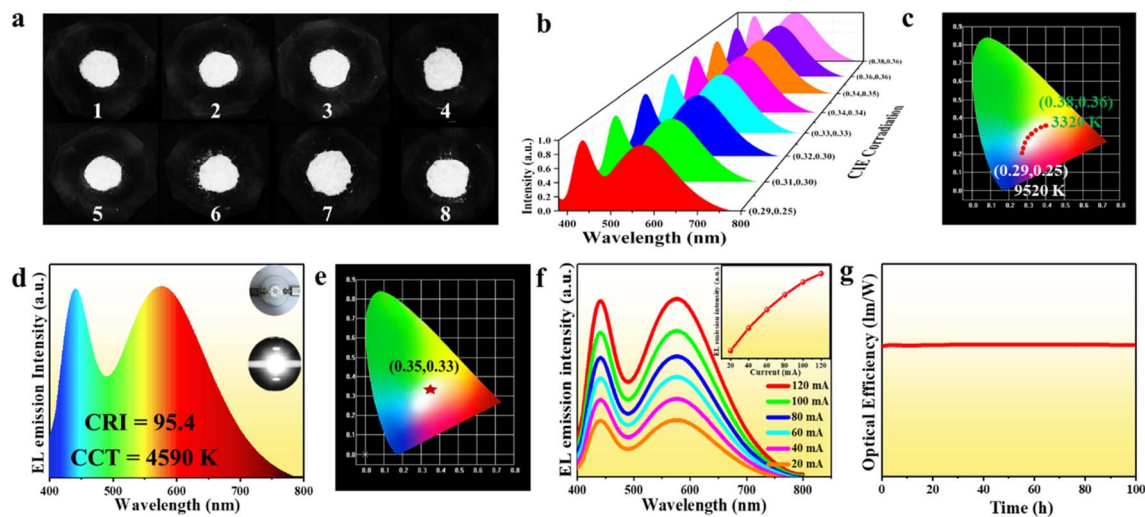


Fig. 4 Characterization of a white LED: (a) photo images of mixed phosphors with varying ratios under 365 nm excitation; (b) PL emission spectra and (c) CIE coordinates of mixed phosphors with varying ratios; (d) EL spectrum of the fabricated white LED (inset: photographs of the fabricated WLED with power off and on); (e) CIE coordinates of the white LED; (f) drive current dependent EL emission spectra; (g) current operating time dependent luminous efficiency.

white LED (Table S3†). Finally, to evaluate the operating stability of the as-prepared LED, we monitor the EL emission spectra along with operating time under a drive current of 20 mA as shown in Fig. S20.† It can be clearly seen that the EL emission spectra remain unchanged and the luminous efficacy shows no obvious degradation over 100 hours of operation indicating excellent photostability (Fig. 4g).

The high PLQY, broad emission band and large Stokes shift demonstrate the potential of $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ as a promising candidate of X-ray scintillators. We firstly plot the absorption spectra of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ and commercial Ce:LuAG toward X-ray in a broad range of photon energy based on the photon cross-section database (Fig. S21†). Based on the calculation of the X-ray absorption coefficients (α)

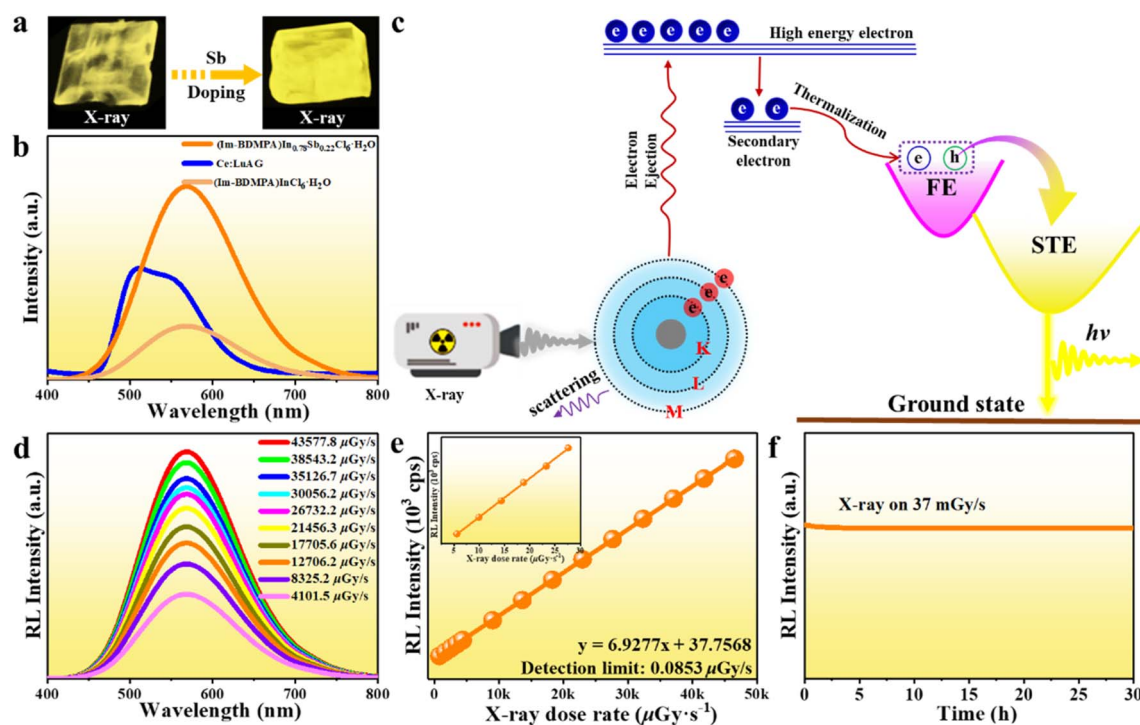


Fig. 5 X-ray scintillation performance of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$: (a) photo images of bulk crystals under X-ray irradiation; (b) RL spectra under 30 kV X-ray excitation; (c) proposed radioluminescence mechanism; (d) X-ray dose rate dependent RL emission spectra; (e) linear dependence of RL emission intensity vs. X-ray dose rate; (f) monitored RL emission intensity under continuous X-ray irradiation.



feasibility of applications in X-ray imaging. As a proof of concept, we employed X-ray imaging by using an (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ based thin screen on a home-made X-ray imaging optical system, and a series of small devices are selected as target objects. As shown in Fig. 6a, an encapsulated fuse tube containing wire was exposed to X-ray illumination, and the different X-ray absorption abilities of the wire and glass tube result in bright spatial intensity contrast, which is translated by the scintillation screen to form optical images with the assistance of a digital camera. Therefore, the inside wire clearly appears in an optical image by using the (Im-BDMPA) $\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ screen. Similarly, when a ball pen containing metallic spring, metallic device and electronic chip were exposed to X-ray irradiation, all the metallic components can be clearly seen in optical images with an enough contrast ratio on the scintillation screen (Fig. 6b–d).

To obtain the spatial resolution of the scintillation screen, a standard X-ray resolution test pattern plate was adopted to perform the X-ray imaging and the observation limit is almost 20 lp per mm (Fig. 6e). The modulation transfer function (MTF) of the scintillation screen was further employed on the X-ray image of a slanted-edge to obtain more accurate spatial resolution (Fig. 6f). The spatial resolution of the screen is extracted to be 17.25 lp per mm when MTF is equal to 0.2, which is obviously superior to that of commercial CsI(Tl) (10 lp per mm), and metal halide scintillators of CsPbBr₃:Lu (16.8 lp per mm), CsPbBr₃:Eu (15 lp per mm), BA₂PbBr₄:10%Mn (10.7 lp per mm),

Rb₂AgBr₃ (10.2 lp per mm), MAPbBr₃ (9.8 lp per mm), CsCu₂I₃ (7.5 lp per mm), *etc.* (Fig. 6g).^{35,50,56–61} Finally, considering the fact that a long RL emission lifetime would result in a strong image lag or ghosting after ceasing of X-rays, it is important to test the RL afterglow to evaluate the image contrast.^{62,63} As shown in Fig. 6h, the emission intensity of the RL afterglow signal rapidly decreases to zero in 0.48 ms after ceasing of X-ray excitation demonstrating high imaging contrast. Overall, the high spatial resolution and negligible afterglow signal indicate the excellent X-ray imaging performance of the (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ based scintillation screen.

The soft and impressible 0D crystal structure of the halide inspires us to further investigate the external stimulus responsive luminescence switching phenomenon toward various small chemical molecules as a possible fluorescent probe. Herein, we select the (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ based thin film as a platform to investigate the PL switching performance, which displays the same luminescence as that of bulk crystals but possesses more operability for sensing applications (Fig. 2f). To validate the sensing performance of (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$, the PL emission spectra were monitored before and after exposing the thin film to various organic solvents over several hours. Herein, a series of small halohydrocarbon molecules or derivatives were selected as sensing targets including chloroacetic acid (CAA), dichloroacetic acid (DCAA), chloropropiophenone (CPP), dibromomethane (DBM), bromodichloromethane (BDCM), dichloromethane (DCM),

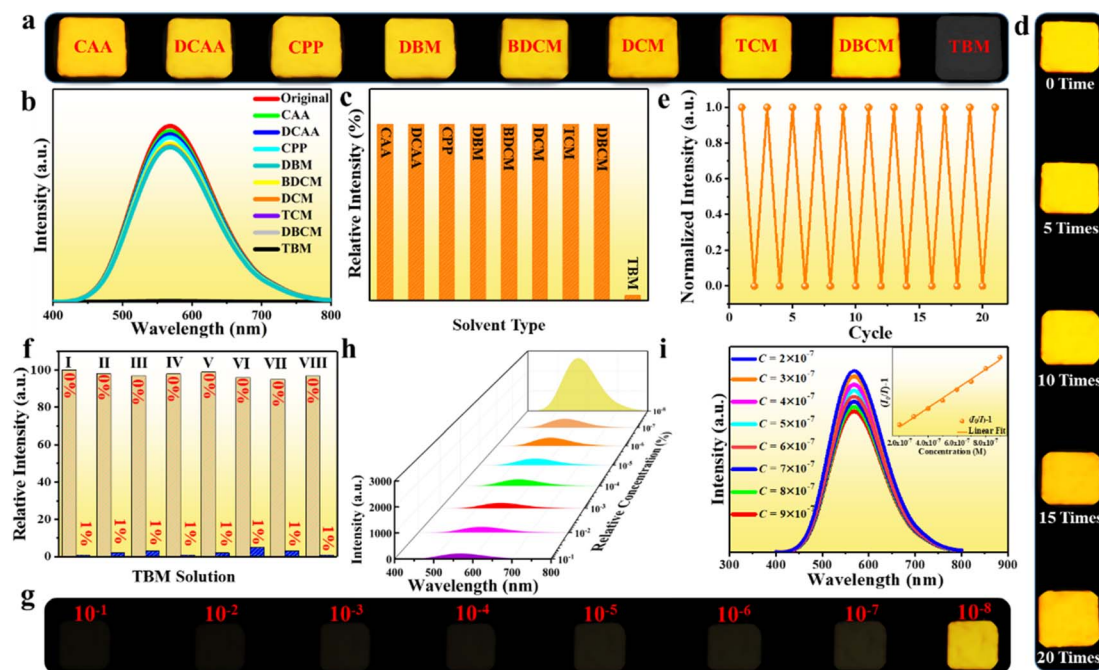


Fig. 7 Application of the fluorescent probe: (a) photo images of the film after exposing to various organic solvents; (b) PL emission spectra and (c) normalized emission intensity of the thin film after exposing to organic solvents; (d) photo images and (e) PL emission intensity of the film during quenching–recovering cycles in TBM as a function of cycle number; (f) normalized luminescence intensity histogram of the film after exposed to mixed solutions of TBM and other organic solvents with concentrations of 0% and 1% (I) CAA; (II) DCAA; (III) CPP; (IV) DBM; (V) BDCM; (VI) DCM; (VII) TCM; (VIII) DBCM); (g) photo images and (h) PL emission spectra of the film after exposing to CTC solutions with low concentrations of TBM from 10^{-1} to 10^{-8} by volume; (i) PL emission spectra of the thin film after soaking in CTC solutions with different concentrations of TBM from 2×10^{-7} to 9×10^{-7} by volume (inset: linear fitting of emission intensity ratio vs. TBM concentration).



trichloromethane (TCM), dibromo-monochloro-methane (DBCM) and tribromomethane (TBM). As shown in Fig. 7a, the photo images of the thin film under UV light irradiation reveal that the fluorescence is rapidly quenched by TBM in less than one second, whereas those of others still exhibit the same bright yellow light luminescence. Detailed PL emission spectra demonstrate that the luminescence intensity of the film in TBM solvent are almost completely quenched, whereas those in other organic solvents are nearly unchanged (Fig. 7b and c). To further inspect the sensing selectivity, substantial organic solvents containing different functional groups were selected as contrast targets including alcohol, acetonitrile, acetone, tetrahydrofuran, acetylacetone, aromatic hydrocarbon (e.g., benzene, dimethylbenzene, chlorobenzene, and nitrobenzene), etc. As shown in Fig. S22,† the (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O films display the same broad yellow emission bands as that of the freshly prepared sample with almost identical emission intensities. These contrast experiments demonstrate that the fluorescence of (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O is solely quenched by TBM but failed for other organic solvents. More excitedly, the quenched fluorescence of the thin film by TBM can be recovered to the original yellow emission after washing with carbon tetrachloride (CTC), and the PL emission intensity can reach up to nearly 100% of original data (Fig. S23†). To more accurately confirm the repeatability of the reversible quenching–recovering process, we monitor the varied PL emission intensity of the (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O film during consecutive impregnation–washing cycles. As shown in Fig. 7d, the thin film displays a repeatable PL quenching–recovering cycle and the luminescence is able to persistently return to the original yellow color after washing with CTC even after consecutive 20 cycles. Simultaneously, the negligible decrease of emission intensity also indicates high reversibility and repeatability (Fig. 7e). After exposing to these organic solvents, the PXRD patterns reveal strong diffraction peaks with a high crystalline degree, indicating a stable crystal structure lattice (Fig. S24–S26†). Therefore, (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O displays reversible TBM responsive fluorescence on/off switching, which indicates the feasibility of the fluorescent probe to detect TBM.

The sharply contrasting response to TBM and other organic solvents inspires us to investigate the selectivity for sensing applications, and a series of anti-interference experiments were performed in mixed solutions of TBM and other halo-hydrocarbon solvents. As depicted in Fig. S27† and 7f, the PL emission intensities of the film were almost completely quenched after exposing to mixed solutions containing a small amount of TBM (1%) but failed in TBM free solutions, which manifest that (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O possesses an excellent sensing selectivity toward TBM. The sensitivity of the fluorescent probe is another crucial indicator to evaluate the sensing performance in practical applications. To explore the sensitivity of the fluorescent probe, a series of dilute TBM/CTC solutions with very low concentrations from 10⁻¹ to 10⁻⁸ by volume were further blended as representative targets. As shown in Fig. 7g and h, both the photo images and PL emission spectra indicate that the film remains to exhibit the PL

quenching phenomenon when the content of TBM is reduced to 10⁻⁷ (0.1 ppm). Detailed PL emission spectra toward ultra-dilute TBM/CTC solutions in the concentration range of 2 × 10⁻⁷ to 9 × 10⁻⁷ indicate that the fluorescence intensity of the film gradually decreases with the increase of TBM concentration, and the quenching effect ($I_0/I - 1$) is linearly dependent on the TBM concentration with a good linear relation ($R^2 = 0.9998$), indicating excellent detection operability (Fig. 7i). These results demonstrate that (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O is a highly desirable fluorescent probe to detect TBM with high selectivity, sensitivity and repeatability.

To illustrate the quenching mechanism toward TBM, the UV-vis absorption spectra were firstly studied on the sample after immersing in various organic solvents. As shown in Fig. S28,† the absorption spectra do not display any change after soaking in most of the organic solvents, while the TBM-treated sample exhibits a more widespread absorption range from 200 nm to 650 nm, which overlaps partially with the emission spectrum of the as-synthesized sample, indicating significant electron exchange and self-absorption characteristics. To further verify the energy transfer between (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O and TBM, X-ray photoelectron spectroscopy (XPS) was performed at the surface of the sample. Compared with the as-synthesized halide, the binding energies of C-2s and N-2s shift slightly to lower energy, while those of Cl-2p, In-3d and Sb-3d shift to higher energy in the TBM treated halide sample (Fig. S29†). All these investigations indicate the energy transfer between (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O and TBM molecules, which consume drastically the excited carriers and quench the luminescence of the halide, and a similar phenomenon has been confirmed in numerous fluorescent probes.⁶⁴

Conclusions

In summary, we herein demonstrate a new 0D hybrid indium/antimony halide as a highly efficient broadband yellow light emitter with near-unity PLQY and multifunctional applications. Firstly, the broadband emission realizes a high-performance white LED with tunable color temperature. Secondly, this halide represents a new X-ray scintillator in 0D hybrid indium halide with promising X-ray imaging applications, as highlighted by the combined merits of a prominent light yield, low detection limit, ultra-high spatial resolution and negligible afterglow time. Thirdly, reversible TBM responsive luminescence off–on switching enables it to be a perfect real-time fluorescent probe to detect TBM with ultrahigh sensitivity, selectivity and repeatability. Therefore, high-performance multiple optoelectronic applications in white LEDs, X-ray scintillation and fluorescence sensors are synchronously realized in a 0D halide structural platform. These multiple applications benefit from the synergistic effects of intrinsic quantum confinement, strong electron–phonon coupling, the sufficient absorption coefficient of X-ray and the impressive structure in the 0D deformable crystal lattice. This work not only deepens the fundamental understanding of the luminescence properties of 0D hybrid halides but also realizes multiple optoelectronic applications. We believe that this



research would guide the rational design of new 0D hybrid metal halides as advanced luminescent materials in cutting-edge optoelectronic fields.

Data availability

The data that support the finding of this study are available from the corresponding author upon reasonable request.

Author contributions

D.-Y. Li and H.-Y. Kang designed the experiments and carried out material synthesis, Y.-H. Liu and J. Zhang assisted in the measurements, Y.-C. Yue helped in data analysis, and D. Yan and X.-W. Lei were responsible for supervision and revising the manuscript. All authors participated in discussing the data and writing the manuscript.

Conflicts of interest

The authors declare no conflict of interest.

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